## **CMOS Voltage Regulator With ON/OFF Switch**

300mA



The MD57XX series is a low-noise LDO that can supply up to 300 mA output current. Designed to meet the requirements of RF and analog circuits, the MD57XX series device provides low noise, high PSRR, low quiescent current, and low line or load transient response figures. Using new innovative design techniques, the MD57XX series offers ultra-low noise performance without a noise bypass capacitor and the ability for remote output capacitor placement. response

figures with a 1-µF input and a 1-µF output ceramic capacitor

#### Features:

Input Voltage Range: 2.2 V to 5.5 V

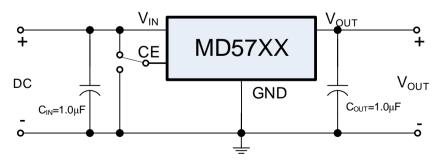
Output Voltage Range: 1.2 V to 4.5 V

- Stable With 1-µF Ceramic Input and Output Capacitors
- · No Noise Bypass Capacitor Required
- Remote Output Capacitor Placement
- Current Limiter and Over Temperature Protection
- -40°C to 125°C Operating Junction Temperature
- Low Output Voltage Noise: 20µV<sub>RMS</sub>
- High PSRR: 90dB@1kHz
- Output Voltage Tolerance: ±2%
- Low quiescent Current: 20uA
- Low Dropout Voltage: 120mV@300mA

### Applications:

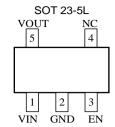
- Mobile Phones, Tablets
- Digital Cameras and Audio Devices
- Portable and Battery-Powered Equipment
- Portable Medical Equipment
- Smart Meters and Field Transmitters
- RF, PLL, VCO, and Clock Power Supplies
- IP Cameras
- Drones

### **■** Typical Application:



## ■ Pin Configuration (Top View):





### **■** Product Selections:

Product Name	V <sub>OUT</sub> (V)	Package	Ordering Name	Marking	Package Information	
MD5712	1.2	DFN1*1-4L	MD57E12WB6	5712		
MD5715	1.5	DFN1*1-4L	MD57E15WB6	5715		
MD5718	1.8	DFN1*1-4L	MD57E18WB6	5718		
MD5721	2.1	DFN1*1-4L	MD57E21WB6	5721	T I D I 40000	
MD5725	2.5	DFN1*1-4L	MD57E25WB6	5725	Tape and Reel, 10000pcs	
MD5728	2.8	DFN1*1-4L	MD57E28WB6	5728		
MD5730	3.0	DFN1*1-4L	MD57E30WB6	5730		
MD5733	3.3	DFN1*1-4L	MD57E33WB6	5733		
MD5736	3.6	DFN1*1-4L	MD57E36WB6	5736		
MD5712	1.2	SOT23-5L	MD57E12QC3	<b>№</b> 5712		
MD5715	1.5	SOT23-5L	MD57E15QC3	<b>№</b> 5715		
MD5718	1.8	SOT23-5L	MD57E18QC3	<b>№</b> 5718		
MD5721	2.1	SOT23-5L	MD57E21QC3	<b>№</b> 5721		
MD5725	2.5	SOT23-5L	MD57E25QC3	<b>№</b> 5725	Tape and Reel, 3000pcs	
MD5728	2.8	SOT23-5L	MD57E28QC3	<b>№</b> 5728		
MD5730	3.0	SOT23-5L	MD57E30QC3	5730		
MD5733	3.3	SOT23-5L	MD57E33QC3	5733		
MD5736	3.6	SOT23-5L	MD57E36QC3	<b>№</b> 5736		

#### Notes:

<sup>1\*</sup> Customer can request to customize the output voltage ranged from 1.2V to 4.5V if desired voltage is not found in the selections.

<sup>2\*</sup> Customer can request customization of package choice.

<sup>3\*</sup> Please pay attention to the MARKING of the product package type.

## **■** Ordering Information

MD57 ①234667 e.g. MD57E33QC3

DESIGNATOR	ITEM	SYMBOL	DESCRIPTION		
1	PIN Configuration	E	Vout NC		
23	Output Voltage	18~	e.g. 1.8V→②=1, ③=8		
4	Packages Type	Q	SOT23		
		W	DFN		
6	Packages Count	A~Z	e.g. A=3, B=4, C=5 ~		
<b>®</b>	Minimum Packing Quantity	0~6	0=100, 1=1000, 2=2500, 3=3000, 4=4000, 5=5000, 6=10000		
7	Customer can request customization of product				

## ■ Absolute Maximum Ratings:

(Unless otherwise indicated: T<sub>a</sub>=25°C)

(					
PARAMETER	SYMBOL	RATINGS		UNITS	
Input Voltage	V <sub>IN</sub>	-0.3 ~ 6.0		V	
Output Voltage	V <sub>OUT</sub>	-0.3 ~ V <sub>IN</sub> +0.3V		V	
Davis Diagination	P <sub>D</sub>	SOT23-5L	250	mW	
Power Dissipation		DFN1*1-4L	200	IIIVV	
Thermal Resistance	R <sub>0JB</sub> (1)	SOT23-5L	180	°C/W	
mermai Resistance		DFN1*1-4L	160	C/VV	
Operating Ambient Temperature	T <sub>opr</sub>	-40 ~ +85		°C	
Storage Temperature	T <sub>stg</sub>	-40 ~ +125		C	
ESD Protection	ESD HBM	6000		V	

Note: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

### ■ Notes on Use:

Input Capacitor (C<sub>IN</sub>): 1.0µF above
Output Capacitor (C<sub>OUT</sub>):1.0µF above

 $<sup>^{(1)}</sup>$  Mounted on JEDEC standard 4layer (2s2p) PCB test board

## ■ Electrical Characteristics:

MD57XX Series

(Unless otherwise indicated:  $T_a=25$ °C)

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Output Voltage	V <sub>OUT(S)</sub>	$V_{IN}=V_{OUT(S)}+2.0V$ $I_{OUT}=1$ mA, $V_{OUT(S)}<2.0V$	V <sub>OUT(S)</sub> -0.03	V <sub>OUT(S)</sub>	V <sub>OUT(S)</sub> +0.03	V	
		$V_{IN}=V_{OUT(S)}+1.0V$ $I_{OUT}=1mA, V_{OUT(S)}\geq 2.0V$	V <sub>OUT(S)</sub> ×0.98	1001(0)	V <sub>OUT(S)</sub> ×1.02		
Dropout Voltage*1	V <sub>DROP</sub>	$V_{EN}=V_{IN}, V_{OUT}<3V$ $I_{OUT}=300$ mA		130		- mV	
		V <sub>EN</sub> =V <sub>IN</sub> , V <sub>OUT</sub> ≥3V I <sub>OUT</sub> =300mA		120		111 V	
Line Regulation	$\frac{\Delta V_{OUT}}{\Delta V_{IN} \bullet V_{OUT(s)}}$	V <sub>OUT(S)</sub> +1.0V≤V <sub>IN</sub> =V <sub>EN</sub> ≤5.5V I <sub>OUT</sub> =10mA		0.02	0.1	%/V	
Line Transient	$\Delta V_OUT\_Line$	V <sub>IN</sub> = V <sub>OUT</sub> +1V to V <sub>OUT</sub> +2V in 30us	-1			- mV	
		$V_{IN}$ = $V_{OUT}$ +2 $V$ to $V_{OUT}$ +1 $V$ in 30us			1		
Load Regulation	$\Delta V_{OUT2}$	$V_{IN}=V_{EN}=V_{OUT(S)}+1.0V$ $1mA \le I_{OUT} \le 300mA$		10	20	mV	
Load Transient	437	I <sub>OUT</sub> =1mA to 300mA in 10µs	-40			mV	
Load Transient	$\Delta V_OUT\_Load$	Ιουτ=300mA to 1mA in 10μs			40		
Temperature Stability	$\frac{\Delta V_{OUT}}{\Delta T_a \bullet V_{OUT(s)}}$	V <sub>IN</sub> =V <sub>EN</sub> =V <sub>OUT(S)</sub> +1.0V I <sub>OUT</sub> =1mA , -40°C≤T <sub>a</sub> ≤125°C		±100		ppm/℃	
GND Current	I <sub>GND</sub>	no load		20	30	μA	
(V <sub>EN</sub> =V <sub>IN</sub> )		I <sub>OUT</sub> =300mA		470		μA	
Shutdown Current	I <sub>SHUT</sub>	V <sub>IN</sub> =5.5V, V <sub>EN</sub> =0		0.01	0.1	μA	
Input Voltage	V <sub>IN</sub>		2.2		5.5	V	
Maximum Output Current	Гоитмах		250	300		mA	
Current Limit*2	ILIM	$V_{IN}=V_{EN}=V_{OUT(S)}+1.0V$ $V_{OUT}=0.95 \times V_{OUT(S)}$		500		mA	
C <sub>OUT</sub> Auto Discharge	Rochg	V <sub>EN</sub> =0, V <sub>OUT</sub> =V <sub>OUT</sub> (S)		240		Ω	
Power Supply		f=1kHz, I <sub>OUT</sub> =20mA		94		- dB	
		f=10kHz, I <sub>OUT</sub> =20mA		72			
Rejection Ratio		f=100kHz, I <sub>OUT</sub> =20mA		77			
		f=1MHz, I <sub>OUT</sub> =20mA		53			
Output noise voltage	en	I <sub>оит</sub> =20mA		20		μV <sub>RMS</sub>	
Start-Up Time	T <sub>START</sub>	From V <sub>EN</sub> >V <sub>ENH</sub> to V <sub>OUT</sub> =95% of V <sub>OUT</sub>		80	150	μs	
Overshoot on Start-Up	$\Delta V_OUT\_Start-up$	Stated as a percentage of V <sub>OUT(S)</sub>			5	%	
EN 'H' Level Voltage	V <sub>ENH</sub>		0.85		5.5	V	
EN 'L' Level Voltage	V <sub>ENL</sub>		0		0.35	٧	
EN 'H' Level Current	I <sub>ENH</sub>	VIN=5.5V, VEN =VIN	-0.1		0.1	μA	
EN 'L' Level Current	I <sub>ENL</sub>	V <sub>IN</sub> =5.5V, V <sub>EN</sub> =0	-0.1		0.1	۳٬۱	
Over Temperature Protection	ОТР	I <sub>OUT</sub> =1mA		155		$^{\circ}$	

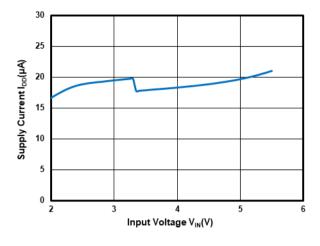
#### Notes:

<sup>1.</sup>  $V_{DROP}=V_{IN1}$  -  $(V_{OUT(S)} \times 0.98)$  where  $V_{IN1}$  is the input voltage when  $V_{OUT}=V_{OUT(S)} \times 0.98$ .

<sup>2.</sup>  $I_{LIM}$ : Output current when  $V_{IN}=V_{OUT(S)}+1V$  and  $V_{OUT}=0.95*V_{OUT(S)}$ .

## **■** Typical Performance Characteristics:

Test Conditions:  $V_{IN}$ =4.3V,  $V_{OUT}$ =3.3V,  $C_{IN}$ =1.0 $\mu$ F,  $C_{OUT}$ =1.0 $\mu$ F,  $T_a$ =25 $^{\circ}$ C, unless otherwise indicated.



0.8

O.2

O.2

VENH Rising

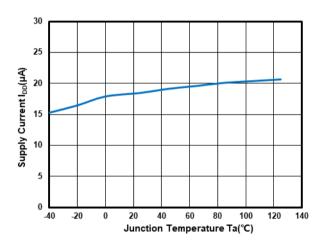
VENL Falling

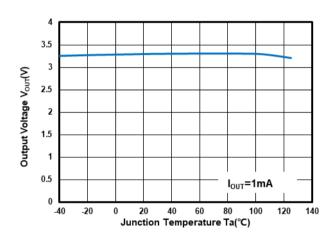
O.2

Input Voltage V<sub>IN</sub>(V)

Supply Current vs. Input Voltage

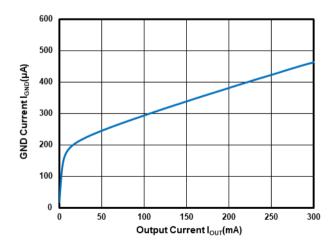
V<sub>EN</sub> Thresholds vs. Input Voltage

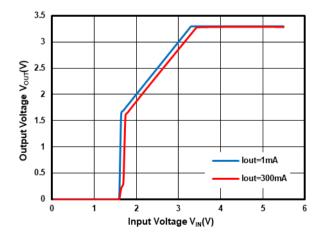




Supply Current vs. Temperature

Output Voltage vs. Temperature



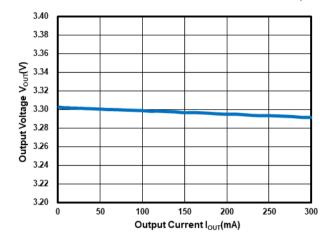


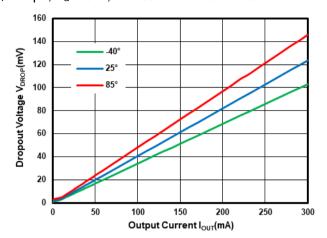
GND Current vs. Output Current

Output Voltage vs. Input Voltage

# **■** Typical Performance Characteristics (Continued):

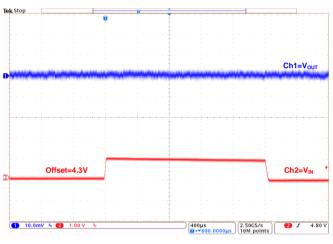
Test Conditions:  $V_{IN}$ =4.3V,  $V_{OUT}$ =3.3V,  $C_{IN}$ =1.0 $\mu$ F,  $C_{OUT}$ =1.0 $\mu$ F,  $T_a$ =25 $^{\circ}$ C, unless otherwise indicated.

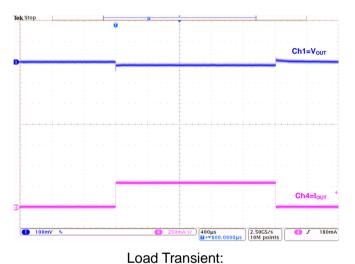




Output Voltage vs. Output Current

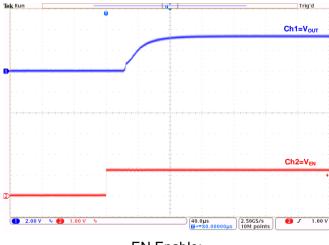
Dropout Voltage vs. Output Current

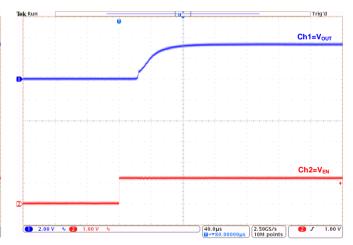




Line Transient: (I<sub>OUT</sub>=10mA)

(I<sub>OUT</sub>=0mA~300mA~0mA)



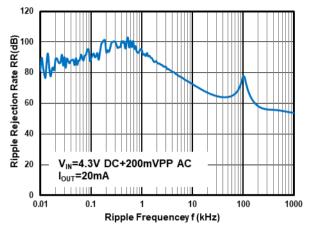


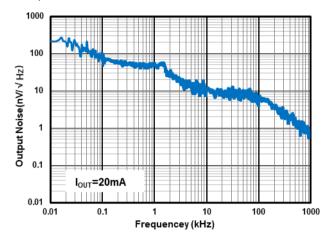
EN Enable: (I<sub>OUT</sub>=0mA)

EN Enable: (I<sub>OUT</sub>=300mA)

## **■** Typical Performance Characteristics (Continued):

Test Conditions:  $V_{IN}$ =4.3V,  $V_{OUT}$ =3.3V,  $C_{IN}$ =1.0 $\mu$ F,  $C_{OUT}$ =1.0 $\mu$ F,  $T_a$ =25 $^{\circ}$ C, unless otherwise indicated.





Power Supply Rejection Ratio

Noise Density Test

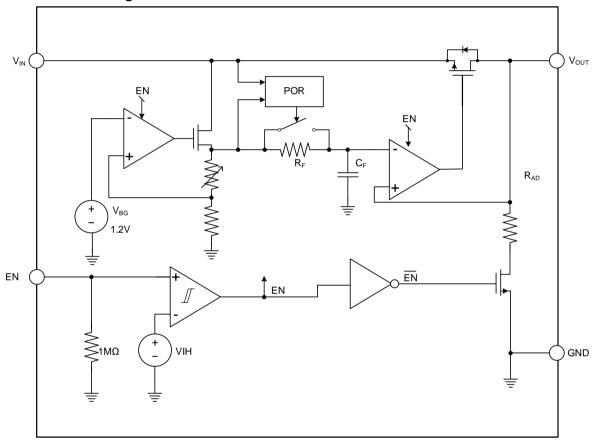
### **■** Detailed Description:

### 1. Overview

Using new innovative design techniques, the MD57XX series offers ultra-low noise performance without the need for a separate noise filter capacitor.

The MD57XX series is designed to perform with a single 1- $\mu$ F input capacitor and a single 1- $\mu$ F ceramic output capacitor. With a reasonable PCB layout, the single 1- $\mu$ F ceramic output capacitor can be placed up to 10 cm away from the MD57XX series device.

### 2. Functional Block Diagram



### **■** Feature Description

#### 1. Enable (EN)

The MD57XX series EN pin is internally held low by a 1-M $\Omega$  resistor to GND. The EN pin voltage must be higher than the V<sub>ENH</sub> threshold to ensure that the device is fully enabled under all operating conditions. The EN pin voltage must be lower than the V<sub>ENL</sub> threshold to ensure that the device is fully disabled and the automatic output discharge is activated.

#### 2. Low Output Noise

Any internal noise at the MD57XX series reference voltage is reduced by a first order low-pass RC filter before it is passed to the output buffer stage. The low-pass RC filter has a –3 dB cut-off frequency of approximately 0.1 Hz.

#### 3. Output Automatic Discharge

The MD57XX series output employs an internal 240- $\Omega$  (typical) pulldown resistance to discharge the output when the EN pin is low, and the device is disabled

#### 4. Remote Output Capacitor Placement

The MD57XX series requires at least a 1-µF capacitor at the OUT pin, but there are no strict requirements about the location of the capacitor in regards the OUT pin. In practical designs, the output capacitor may be located up to 10 cm away from the LDO.

#### 5. Over Temperature Protection (OTP)

Over temperature protection disables the output when the junction temperature rises to approximately 160°C which allows the device to cool. When the junction temperature cools to approximately 135°C, the output circuitry enables. Based on power dissipation, thermal resistance, and ambient temperature, the thermal protection circuit may cycle on and off. This thermal cycling limits the dissipation of the regulator and protects it from damage as a result of overheating.

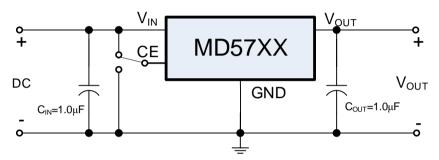
The over temperature protection circuitry of the MD57XX series has been designed to protect against temporary thermal overload conditions. The OTP circuitry was not intended to replace proper heat-sinking. Continuously running the MD57XX series device into thermal shutdown may degrade device reliability.

### ■ Application and Implementation

The MD57XX series is designed to meet the requirements of RF and analog circuits, by providing low noise, high PSRR, low quiescent current, and low line or load transient response figures. The device offers excellent noise performance without the need for a noise bypass capacitor and is stable with input and output capacitors with a value of 1  $\mu$ F. The MD57XX series delivers this performance in industry standard packages such as SOT23-5, for this device, are specified with an operating junction temperature (T<sub>J</sub>) of  $-40^{\circ}$ C to 125°C.

#### 1. Typical Application

As the figure shows the typical application circuit for the MD57XX series. Input and output capacitances may need to be increased above the 1 µF minimum for some applications.



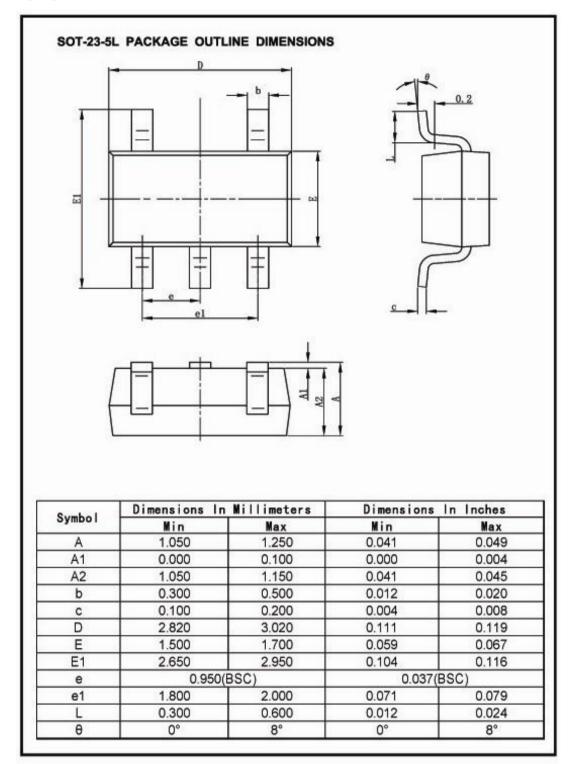
#### 2. Design Requirements

DESIGN PARAMETER	EXAMPLE VALUE		
Input voltage range	2.2 V to 5.5 V		
Output voltage	1.8 V		
Output current	300 mA		
Output capacitor range	1 μF to 10 μF		
Input/Output capacitor ESR range	5 to 500 mΩ		

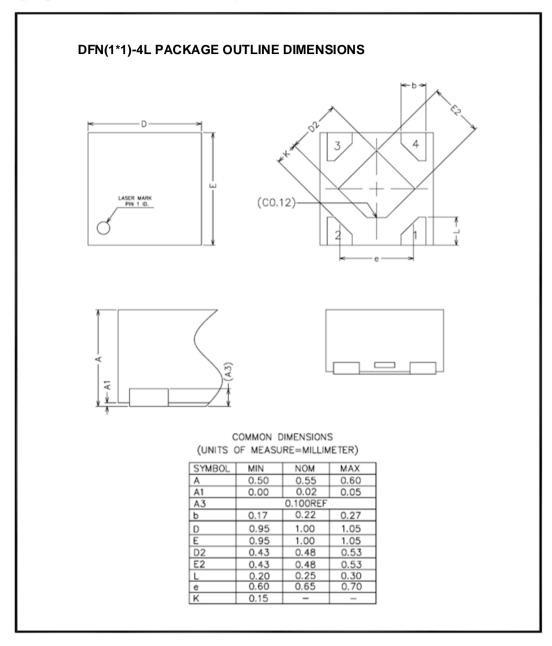
#### Notes:

- 1. If the impedance of the power supply is high, which is caused by forgetting installing input capacitor or installing too small value capacitor, the oscillation may occur.
- Pay attention to the operation conditions of input and output voltage and load current, such that the power consumption
  in the IC should not exceed the allowable power consumption of the package even though the chip has short circuit
  protection.
- 3. IC has a built-in anti-static protection (ESD) circuit, but please do not add excessive stress to the IC.

## ■ Packaging Information



## ■ Packaging Information (Continued)



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